

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	3233898	memory or storage	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/09/28 15:07
L2	349444	1 and (magnetoresistive or magneto-resistive or magnetic or mram)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/09/28 15:08
L3	273	2 and (row or word or wordline) adj3 driv\$5 with current with writ\$5	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/09/28 15:09
L4	5	2 and (row or word or wordline) adj3 driv\$5 with current near3 writ\$5 with (small\$5 or low\$5) with cell	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/09/28 15:14
L5	7	2 and (row or word or wordline) adj3 driv\$5 with current near3 writ\$5 with (small\$5 or low\$5 or great\$5 or larg\$5 or high\$5) with cell	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/09/28 15:15

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	5	((memory or storage) and cell and resistance and (magnetoresistive or magneto-rsistive) and current adj source and writ\$5 near2 current).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/09/28 15:27
L2	0	((memory or storage) and cell and (magnetoresistive or magneto-rsistive) and current adj source and writ\$5 near2 current and drive adj ability).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/09/28 15:28